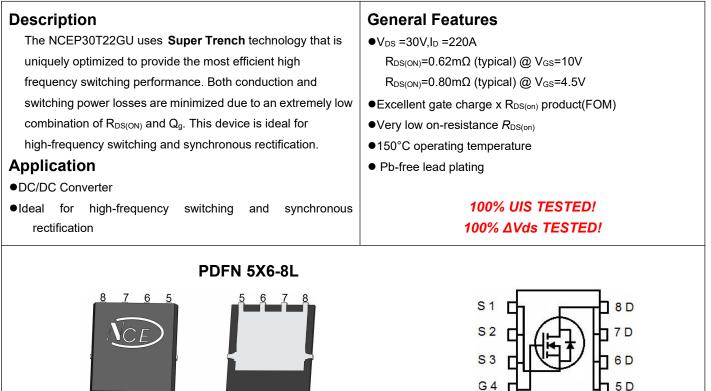
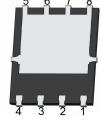


NCE N-Channel Super Trench Power MOSFET



Top View



Bottom View

Schematic Diagram

Package Marking and Ordering Information

Device Marking	Device	Device Package	Reel Size	Tape width	Quantity
P30T22GU	NCEP30T22GU	PDFN5X6-8L	Ø330mm	12mm	5000units

Absolute Maximum Ratings (Tc=25[°]C unless otherwise noted)

Parameter	Symbol	Limit	Unit
Drain-Source Voltage	Vds	30	V
Gate-Source Voltage	Vgs	±20	V
Drain Current-Continuous	Ι _D	220	А
Drain Current-Continuous(T _C =100 ℃)	I _D (100℃)	170	A
Pulsed Drain Current	I _{DM}	880	A
Maximum Power Dissipation	PD	200	W
Derating factor		1.60	W/℃
Single pulse avalanche energy ^(Note 1)	E _{AS}	1880	mJ
Operating Junction and Storage Temperature Range	T_{J},T_{STG}	-55 To 150	°C

Thermal Characteristic

Thermal Resistance, Junction-to-Case	Rejc	0.63	°C/W	
--------------------------------------	------	------	------	--



Electrical Characteristics (Tc=25°C unless otherwise noted)

Parameter	Symbol	Condition	Min	Тур	Мах	Unit
Off Characteristics	·		T			
Drain-Source Breakdown Voltage	BV _{DSS}	V _{GS} =0V I _D =250µA	30		-	V
	T_=25	°C	-	-	1	μA
Zero Gate Voltage Drain Current	IDSS TJ=60	°C V _{DS} =30V,V _{GS} =0V	-	-	2	μA
	T_=12	5°C	-	-	10	μA
Gate-Body Leakage Current	I _{GSS}	V _{GS} =±20V,V _{DS} =0V	-	-	±100	nA
On Characteristics	·	·				·
Gate Threshold Voltage	$V_{GS(th)}$	V _{DS} =V _{GS} ,I _D =250µA	1.0	1.7	2.5	V
		V _{GS} =10V, I _D =100A	-	0.62	0.8	mΩ
Drain-Source On-State Resistance	R _{DS(ON)}	V _{GS} =4.5V, I _D =100A	-	0.80	1.08	mΩ
Forward Transconductance	g fs	V _{DS} =5V,I _D =100A		100	-	S
Dynamic Characteristics	·	·				
Input Capacitance	C _{lss}		-	6950	-	PF
Output Capacitance	Coss		-	2670	-	PF
Reverse Transfer Capacitance	Crss	F=1.0MH2	-	130	-	PF
Switching Characteristics (Note 2)			, i			
Turn-on Delay Time	t _{d(on)}		-	12	-	nS
Turn-on Rise Time	tr	V _{DD} =15V,I _D =100A	-	8	-	nS
Turn-Off Delay Time	t _{d(off)}	V _{GS} =10V,R _G =1.6Ω	-	50	-	nS
Turn-Off Fall Time	t _f		-	9	-	nS
Total Gate Charge	Qg		-	106	-	nC
Gate-Source Charge	Qgs		-	15		nC
Gate-Drain Charge	Drain Charge Q _{gd}		-	17		nC
Drain-Source Diode Characteristics						
Diode Forward Voltage (Note 3)	V _{SD}	V _{GS} =0V,I _S =100A	-		1.2	V
Diode Forward Current (Note 2)	Is		-	-	220	Α
Reverse Recovery Time	t _{rr}	TJ = 25°C, IF =Is	-	32	-	nS
Reverse Recovery Charge	Qrr	di/dt = 100A/µs	-	110	-	nC

Notes:

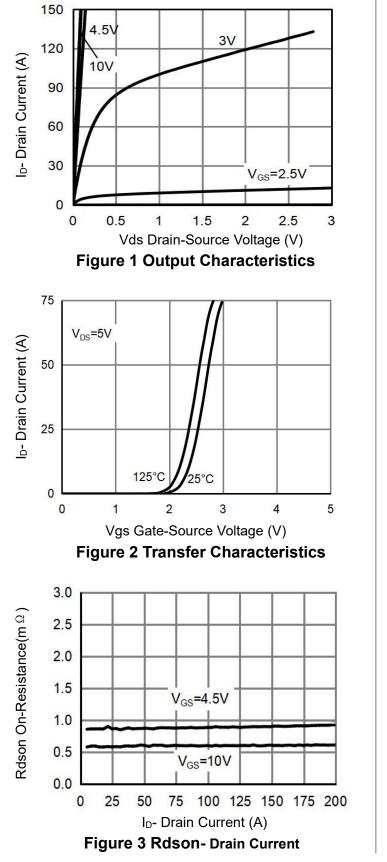
1. EAS condition : Tj=25 $^\circ \! \mathrm{C}, V_{DD}$ =15V,V_G=10V,L=0.5mH,Rg=25 Ω

2. Guaranteed by design, not subject to production

3. These curves are based on the junction-to-case thermal impedance which is measured with the device mounted to a large heatsink, assuming a maximum junction temperature of T_{J(MAX)}=150°C. The SOA curve provides a single pulse rating.



Typical Electrical and Thermal Characteristics



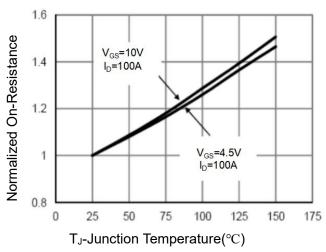


Figure 4 Rdson-Junction Temperature

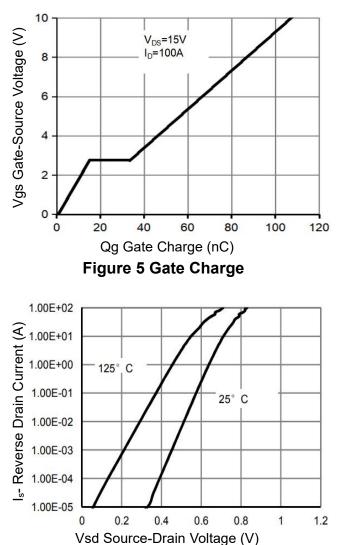


Figure 6 Source- Drain Diode Forward



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NCEP30T22GU

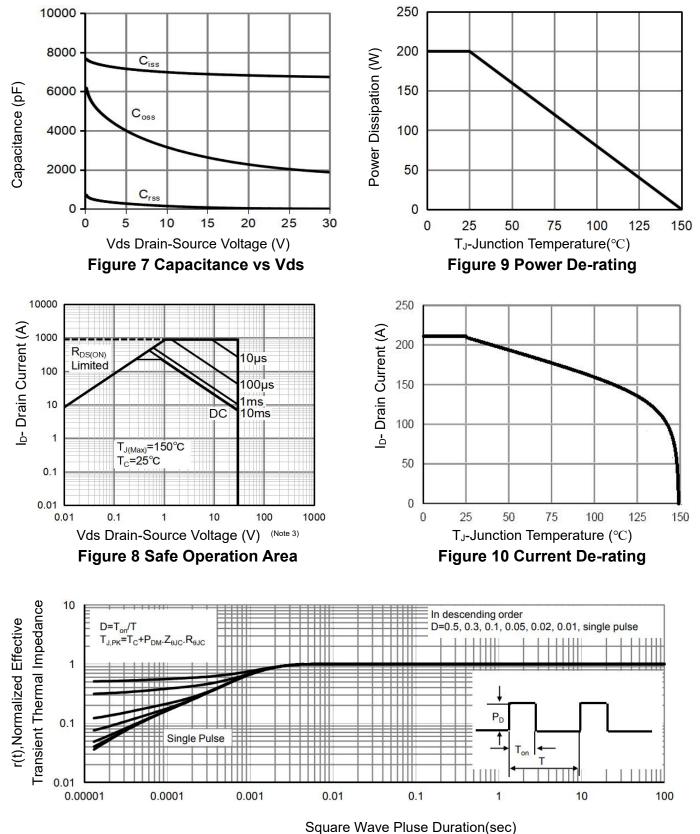


Figure 11 Normalized Maximum Transient Thermal Impedance

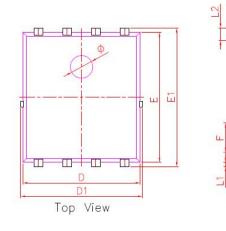


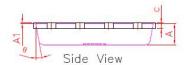
E2

b

Bottom View

PDFN5X6-8L(E) Package Information

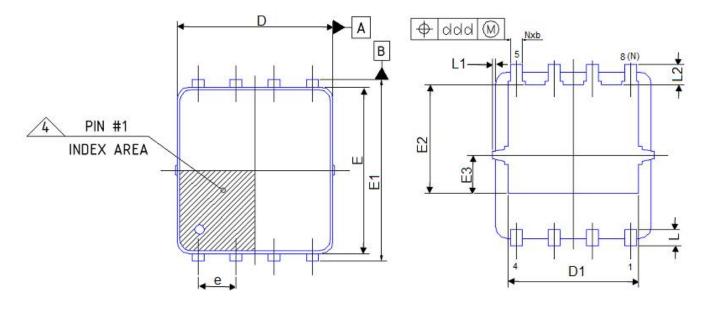




DIM.	MIN.	NOM.	MAX.	
А	0.90	0.95	1.00	
A1	0.00	0.02	0.05	
b	0.35	0.40	0.50	
с	0.20	0.25	0.30	
D	5.10	5.20	5.30	
D1	5.10	5.40	5.50	
D2	4.25	4.35	4.45	
е		1.27 BSC		
Е	5.70	5.75	5.80	
E1	6.00	6.15	6.30	
E2	3.57	3.67	3.77	
F	1.18	1.28	1.38	
L	0.55	0.65	0.75	
L1	0.15	0.20	0.25	
L2	0.45	0.55	0.65	
ø	0.90	1.00	1.10	
Θ	8"	10*	12*	

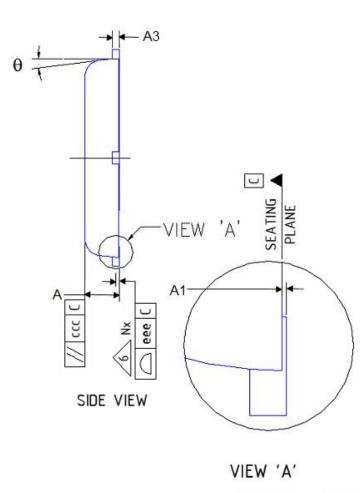


PDFN5X6-8L(f) Package Information



TOP VIEW

BOTTOM VIEW



		limension	Table	
Thickness Symbol A		NOTE		
mbol	MINIMUM	NOMINAL	MAXIMUM	
Α	0.85	0.95	1.00	
A1	0.00		0.05	
A3		0.2 Ref		
b	0.30	0.40	0.50	
D	5.10	5.20	5.30	
E	5.45	5.55	5.65	
e		1.27 BSC		
D1	4.25	4.35	4.45	
E1	5.95	6.05	6.15	
E2	3.525	3.625	3.725	
E3	1.175	1.275	1.375	
L	0.45	0.55	0.65	
L1	0		0.15	
L2		0.68 REF		
θ	0°		10°	
aaa		0.05		
bbb				
	0.10			
ddd	0.05			
eee	0.08 8 4 1,2			
N				
ND				
NOTES				



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